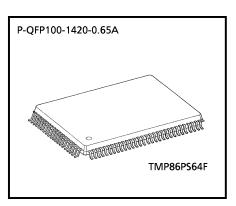
CMOS 8-Bit Microcontroller

TMP86PS64F

The TMP86PS64F is a OTP type MCU which includes 60 Kbytes One-time PROM. It is a pin compatible with a mask ROM product of the TMP86CS64F. Writing the program to built-in PROM, the TMP86PS64F operates as the same way as the TMP86CS64F. Using the Adapter socket, you can write and verify the data for the TMP86PS64F with a general-purpose PROM programmer same as TC571000D/AD.

Product No. ROM		RAM	Package	Adapter Socket
TMP86PS64F	60 K×8 bits	2 K × 8 bits	P-QFP100-1420-0.65A	BM11190



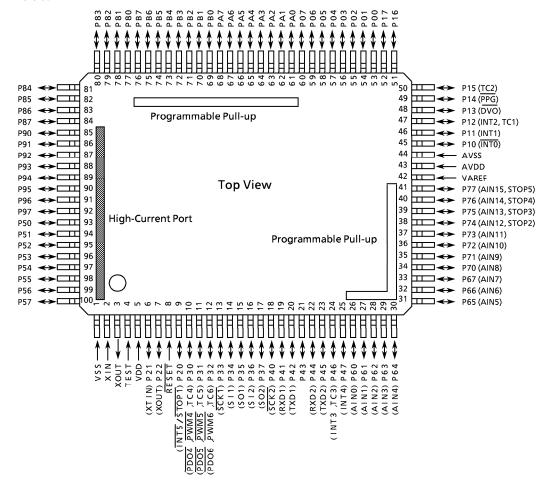
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86PS64-1 2002-09-11

Pin Assignments (Top View)

P-OFP100-1420-0.65A



86PS64-2 2002-09-11

Pin Function

The TMP86PS64 has MCU mode and PROM mode.

(1) MCU mode

In the MCU mode, the TMP86PS64F is a pin compatible with the TMP86CS64F (Mask sure to fix the TEST pin to "L" level).

(2) PROM mode

Pin Name	Input/Output	Functions	Pin Name (MCU mode)		
A16 to A15			P17 to P16		
A14 to A7	Input	Input of Memory address for program	P77 to P70		
A6 to A0			P67 to P61		
D7 to D0	1/0	Input/Output of Memory data for program	P57 to P50		
CE		Chip enable	P13		
ŌĒ	Input	Output enable	P14		
PGM		Program control	P15		
VPP		+ 12.75V/5V (Power supply of program)	TEST		
vcc	Power supply	+ 6.25V/5V	VDD		
GND		0V	VSS		
P11, P21, AVDD		PROM mode setting pin. Fix to "H".			
P00, P10, P20, P22, AVSS, VAREF	1/0	PROM mode setting pin. Fix to "L".			
RESET					
P07 to P01					
P37 to P30					
P47 to P40					
P87 to P80	1/0	Open			
P97 to P90					
PA7 to PA0					
PB7 to PB0					
XIN	Input	Colf assillation with vacanatas (46 Balla)			
XOUT	Output	Self oscillation with resonator (16 MHz).			

Operation

This section describes the functions and basic operational blocks of TMP86PS64F.

The TMP86PS64F has PROM in place of the mask ROM which is included in the TMP86CS64F. The configuration and function are same as the TMP86CS64F. For TMP86CS64F, however, some functions have been partially changed or deleted. For the function of TMP86PS64F in details, see the section of TMP86CS64F

In addition, TMP86PS64F operates as the single clock mode when releasing reset.

When using the dual clock mode, oscillate a low-frequency clock by SET. XTEN command at the beginning of program.

1. Operating Mode

The TMP86PS64F has MCU mode and PROM mode.

1.1 MCU Mode

The MCU mode is set by fixing the TEST/VPP pin to the "L" level (TEST/VPP pin cannot be used open because it has no built-in pull-down resister).

1.1.1 Program memory

The TMP86PS64F has a 60 Kbyte built-in one time PROM (addresses 1000 to FFFFH in the MCU mode, addresses 0000 to EFFFH in the PROM mode).

When using TMP86PS64F for evaluation of TMP86CS64F, the program is written in the program storing area shown in Figure 1-1.

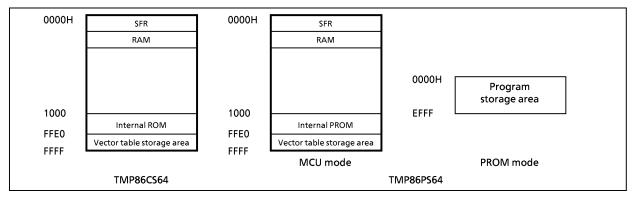


Figure 1-1. Program Memory Area

Note: The area that is not in use should be set data to FFH, or a general-purpose PROM programmer should be set only in the program memory area to access.

1.1.2 Data Memory

TMP86PS64 has a built-in 2-Kbyte data memory (static RAM).

1.1.3 Input/Output Circuity

(1) Control pins

The control pins of the TMP86PS64 are the same as those the TMP86CS64 except that the TEST pin does not have a built-in pull-down resistor.

(2) I/O ports

The I/O circuities of TMP86PS64 I/O ports are the same as those of TMP86CS64.

Electrical Characteristics

Absolute Maximum Ratings $(V_{SS} = 0 V)$

Parameter	Symbol	Pins	Ratings	Unit
Supply Voltage	V _{DD}		- 0.3 to 6.5	
Programming Voltage	V _{PP}		- 0.3 to 13	1
Input Voltage	V _{IN}		- 0.3 to V _{DD} + 0.3	1 V
Output Voltage	V _{OUT}		- 0.3 to V _{DD} + 0.3	
	Гоитн	Except Open-drain	- 3.2	
Output Current (Bor 1 nin)	I _{OUT1}	Except Port P5, P9	3.2	
Output Current (Per 1 pin)	I _{OUT2}	Port P5		
	Гоитз	Port P9	30	mA
	Σl _{OUT1}	Except Port P5, P9		
Output Current (Total)	ΣI _{OUT2}	Port P5	60	
	ΣI _{OUT3}	Port P9]	
Power Dissipation [T _{opr} = 85°C]	PD		250	mW
Soldering Temperature (time)	Tsld		260 (10 s)	
Storage Temperature	Tstg		– 55 to 125	°c
Operating Temperature	Topr		- 40 to 85	

Note: The absolute maximum ratings are rated values which must not be exceeded during operation, even for an instant. Any one of the ratings must not be exceeded. If any absolute maximum rating is exceeded, a device may break down or its performance may be degraded, causing it to catch fire or explode resulting in injury to the user. Thus, when designing products which include this device, ensure that no absolute maximum rating value will ever be exceeded.

Recommended Operating Condition $(V_{SS} = 0 \text{ V}, \text{Topr} = -40 \text{ to } 85^{\circ}\text{C})$

Parameter	Symbol	Pins	С	ondition	Min	Max	Unit	
			fc = 1 to 16 MHz	Each operation modes	4.5	5.5		
Supply Voltage	V _{DD}		fc = 1 to 8 MHz	Each operation modes	2.7	5.5		
			fs = 32.768 kHz	Each operation modes	2.7	5.5		
			STOP mode		2.0	5.5	V	
	V _{IH1}	Except hysteresis input	$V_{DD} \ge 4.5 \text{ V}$ $V_{DD} < 4.5 \text{ V}$		$V_{DD} \times 0.70$			
Input high Level	V _{IH2}	Hysteresis input			$V_{DD} \times 0.75$	V_{DD}		
	V _{IH3}				$V_{DD} \times 0.90$			
	V _{IL1}	Except hysteresis input	,,	> 4.5.7		$V_{DD} \times 0.30$	Ī	
Input low Level	V _{IL2}	Hysteresis input]	_{DD} ≧ 4.5 V	0	V _{DD} × 0.25	1	
	V _{IL3}		V _C	_{DD} < 4.5 V		$V_{DD} \times 0.10$		
	fc	fc XIN, XOUT		V _{DD} = 4.5 to 5.5 V		16.0	NAM-	
Clock Frequency	''			V _{DD} = 2.7 to 5.5 V		8.0	MHz	
	fs	XTIN, XTOUT			30.0	34.0	kHz	

 $Note: \ The \ recommended \ operating \ conditions \ for \ a \ device \ are \ operating \ conditions \ under \ which \ it \ can \ be \ guaranteed \ that$ the device will operate as specified. If the device is used under operating conditions other than the recommended operating conditions (supply voltage, operating temperature range, specified AC/DC values etc.), malfunction may occur. Thus, when designing products which include this device, ensure that the recommended operating conditions for the device are always adhered to.

DC Characteristics $(V_{SS} = 0 \text{ V}, \text{Topr} = -40 \text{ to } 85^{\circ}\text{C})$

Parameter	Symbol	Pins	Condition	Min	Тур.	Max	Unit
Hysteresis Voltage	V _{HS}	Hysteresis input		_	0.9	_	V
	I _{IN1}	TEST					
Input Current	I _{IN2}	Sink Open Drain, Tri-state port	V _{DD} = 5.5 V, V _{IN} = 5.5 V/0 V	_	_	± 2	μΑ
	I _{IN3}	STOP, RESET					
	R _{IN1}	RESET		100	220	450	
Input Resistance	R _{IN2}	Programmable pull up (P6, P7, PA, PB)	V _{DD} = 5.5 V	40	80	200	kΩ
OSC. Feedback	Rfx	XIN-XOUT		_	1.2	-	
resistance	Rfxt	XTIN-XTOUT		_	6	_	ΜΩ
Output Leakage	I _{LO1}	Sink Open Drain port	V _{DD} = 5.5 V, V _{OUT} = 5.5 V	_	-	2	
Current	I _{LO2}	Tri-state port	V _{DD} = 5.5 V, V _{OUT} = 5.5 V/0 V	_	-	± 2	μ Α
"H" output Voltage	I" output Voltage V _{OH} Tr		$V_{DD} = 4.5 \text{ V}, I_{OH} = -0.7 \text{ mA}$	4.1	-	_	
"L" output Voltage	V _{OL3}	Except XOUT, P5, P9	$V_{DD} = 4.5 \text{ V}, I_{OL} = 1.6 \text{ mA}$	_	-	0.4	V
#1.# - 1 - 1 C 1	I _{OL1}	Except XOUT, P5, P9	$V_{DD} = 4.5 \text{ V}, V_{OL} = 0.4 \text{ V}$	_	1.6	-	
"L" output Current	I _{OL3}	High current port (P5, P9)	V _{DD} = 4.5 V, V _{OL} = 1.0 V	_	20	-	
Supply Current in Normal 1, 2 mode			V _{DD} = 5.5 V V _{IN} = 5.3 V/0.2 V	-	9	10	mA
Supply Current in IDLE 1, 2 mode			fc = 16 MHz fs = 32.768 kHz	_	5	6	
Supply Current in SLOW 1 mode	I _{DD}		V _{DD} = 3.0 V	_	20	30	
Supply Current in	\dashv		$V_{IN} = 2.8 \text{ V}/0.2 \text{ V}$ fs = 32.768 kHz	_	10	20	μA
SLEEP 0, 1 mode					'	20	~~
Supply Current in STOP mode			$V_{DD} = 5.5 \text{ V}$ $V_{IN} = 5.3 \text{ V}/0.2 \text{ V}$	_	0.5	10	

Note 1: Typical values show those at Topr = 25°C, $V_{DD} = 5$ V

Note 2: Input current ($I_{[N]}$, $I_{[N]}$); The current through resistor is not included, when the input resistor (pull-up or pull-down) is contained.

Note 3: IDD; Except for IREF.

AD Conversion Characteristics

(Vss = 0 V, 4.5 V \leq VDD \leq 5.5 V, Topr = -40 to 85°C)

Parameter	Symbol	Condition	Min	Тур.	Max	Unit
Analog Reference Voltage	V _{AREF}		A _{VDD} – 1.0	-	A _{VDD}	
Power Supply Voltage of	A _{VDD}			V_{DD}		
Analog Control Circuit	A _{VSS}			V_{SS}] ,,
Analog Reference of Voltage Range (Note 4)	$\triangle V_{AREF}$		3.5	-	V _{DD}	V
Analog Input Voltage	V _{AIN}		V _{SS}	-	V _{AREF}	
Power Supply Current of Analog Reference Voltage	I _{REF}	$V_{DD} = A_{VDD} = V_{AREF} = 5.5 \text{ V}$ $V_{SS} = A_{VSS} = 0.0 \text{ V}$	-	0.6	1.0	mA
Non linearity Error			-	_	± 2	
Zero Point Error		$V_{DD} = A_{VDD} = 5.0 \text{ V}$	-	_	± 2]
Full Scale Error		$V_{SS} = A_{VSS} = 0.0 \text{ V}$ $V_{ARFF} = 5.0 \text{ V}$	-	-	± 2	LSB
Total Error			_	_	± 4]

$$(V_{SS} = 0 \text{ V}, 2.7 \text{ V} \le V_{DD} < 4.5 \text{ V}, Topr = -40 \text{ to } 85^{\circ}\text{C})$$

Parameter	Symbol	Condition	Min	Тур.	Max	Unit
Analog Reference Voltage	V _{AREF}		A _{VDD} – 1.0	-	A _{VDD}	
Power Supply Voltage of	A _{VDD}			V_{DD}]
Analog Control Circuit	A _{VSS}			V _{SS}] ,,
Analog Reference of Voltage Range (Note 4)	$\triangle V_{AREF}$		2.5	_	V _{DD}	V
Analog Input Voltage	V _{AIN}		V _{SS}	_	V _{AREF}]
Power Supply Current of Analog Reference Voltage	I _{REF}	$V_{DD} = A_{VDD} = V_{AREF} = 4.5 \text{ V}$ $V_{SS} = A_{VSS} = 0.0 \text{ V}$	-	0.5	0.8	mA
Non linearity Error			-	-	± 2	
Zero Point Error		$V_{DD} = A_{VDD} = 2.7 \text{ V}$	_	_	± 2] , , ,
Full Scale Error		$V_{SS} = A_{VSS} = 0.0 \text{ V}$ $V_{ARFF} = 2.7 \text{ V}$	_	_	± 2	LSB
Total Error		1	_	_	± 4]

Note 1: The total error includes all errors except a quantization error, and is defined as a maximum deviation from the ideal conversion line.

Note 2: Conversion time is different in recommended value by power supply voltage.

About conversion time, please refer to "2.14.2 Register Framing".

Note 3: Please use input voltage to AIN input Pin in limit of V_{AREF} - V_{SS}.

When voltage of range outside is input, conversion value becomes unsettled and gives affect to other channel conversion value.

Note 4: Analog Reference Voltage Range: $\triangle V_{AREF} = V_{AREF} - A_{VSS}$

AC Characteristics

 $(V_{SS} = 0 \text{ V}, V_{DD} = 4.5 \text{ to } 5.5 \text{ V}, Topr = -40 \text{ to } 85^{\circ}\text{C})$

Parameter	Symbol	Condition	Min	Тур.	Max	Unit
		NORMAL 1, 2 mode	0.05			
		IDLE 0, 1, 2 mode	0.25	_	4	
Machine Cycle Time	SLOW 1, 2 mode SLEEP 0, 1, 2 mode	SLOW 1, 2 mode		_	133.3	μS
		SLEEP 0, 1, 2 mode	117.6			
High Level Clock Pulse Width	t _{WCH}	For external clock operation (XIN input)		24.05		
Low Level Clock Pulse Width	t _{WCL} fc = 16 MHz		_	31.25	-	ns
High Level Clock Pulse Width	t _{WSH}	For external clock operation (XTIN input)		15.26		
Low Level Clock Pulse Width	t _{WSL}	fs = 32.768 kHz	ı		ı	μS

$(V_{SS} = 0 \text{ V}, V_{DD} = 2.7 \text{ to } 4.5 \text{ V}, Topr = -40 \text{ to } 85^{\circ}\text{C})$

Parameter	Symbol	Condition	Min	Тур.	Max	Unit
		NORMAL 1, 2 mode	٠.			
Machine Cycle Time		IDLE 0, 1, 2 mode	0.5	_	4	
	tcy	SLOW 1, 2 mode		_	133.3	μ S
		SLEEP 0, 1, 2 mode	117.6			
High Level Clock Pulse Width	t _{WCH}	For external clock operation (XIN input)		60.5		
Low Level Clock Pulse Width	t _{WCL}	fc = 8 MHz	_	62.5	_	ns
High Level Clock Pulse Width	t _{WSH}	For external clock operation (XTIN input)	-			
Low Level Clock Pulse Width	t _{WSL}	fs = 32.768 kHz		15.26	-	μS

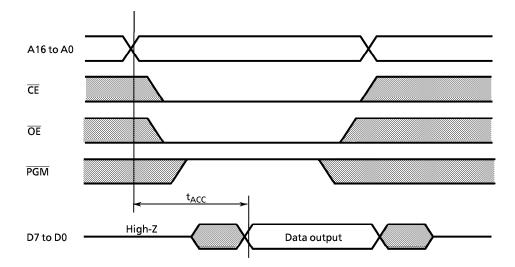
DC Characteristics, AC Characteristics (PROM Mode)

 $(V_{SS} = 0 \text{ V, Topr} = 25 \pm 5^{\circ}\text{C})$

(1) Read operation in PROM mode

Parameter	Symbol	Conditions	Min	Тур.	Max	Unit
High level input voltage (TTL)	V _{IH4}		2.2	-	V _{CC}	
Low leve input voltage (TTL)	V _{IL4}		0	-	0.8	,,
Power supply	V _{CC}		4.75	5.0	5.25	V
Power supply of program	V _{PP}		4.73	3.0	3.23	
Address access time	t _{ACC}	V _{CC} = 5.0 ± 0.25 V	_	1.5tcyc + 300	_	ns

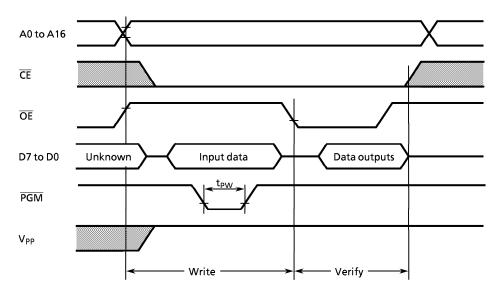
Note: tcyc = 250 ns at 16 MHz



(2) Program operation (High-speed) (Topr = $25 \pm 5^{\circ}$ C)

Parameter	Symbol	Conditions	Min	Тур.	Max	Unit
High level input voltage (TTL)	V _{IH4}		2.2	- -	V _{CC}	
Low leve input voltage (TTL)	V _{IL4}		0	_	0.8	v
Power supply	V _{CC}		6.0	6.25	6.5	\ \ \
Power supply of program	V _{PP}		12.5	12.75	13.0	
Pulse width of initializing program	t _{PW}	V _{CC} = 6.0 V	0.095	0.1	0.105	ms

High-speed program



- Note 1: The power supply of V_{PP} (12.75 V) must be set power-on at the same time or the later time for a power supply of V_{CC} and must be clear power-on at the same time or early time for a power supply of V_{CC} .
- Note 2: The pulling up/down device on the condition of $V_{PP} = 12.75 \text{ V } \pm 0.25 \text{ V}$ causes a damage for the device. Do not pull up/down at programming.
- Note 3: Use the recommended adapter (see 1.2.2 (1)) and mode (see 1.2.2 (3) i).

 Using other than the above condition may cause the trouble of the writting.

Recommended Oscillating Conditions-1

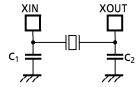
 $(V_{SS} = 0 \text{ V}, V_{DD} = 4.5 \text{ to } 5.5 \text{ V}, \text{ Topr} = -40 \text{ to } 85^{\circ}\text{C})$

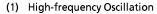
Danamatan	0.33	Oscillation	_			ed Constant
Parameter	Oscillator	Frequency	Recommended Oscillator		C ₁	C ₂
		16 MHz	MURATA	CSA16.00MXZ040	10 pF	10 pF
High francis	Ceramic Resonator	8 MHz	MURATA	CSA8.00MTZ	30 pF	30 pF
High-frequency Oscillation				CST8.00MTW	30 pF (built-in)	30 pF (built-in)
Oscillation		4.19 MHz	MURATA	CSA4.19MG	30 pF	30 pF
		4.19 WITZ		CST4.19MGW	30 pF (built-in)	30 pF (built-in)
Low-frequency	Crystal Oscillator	32.768 kHz	SII	VT-200	6 pF	6 pF
Oscillation	Crystal Oscillator	32.700 KHZ	311	V 1-200	O Pi	o pi

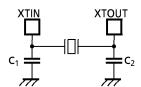
Recommended Oscillating Conditions-2

$$(V_{SS} = 0 \text{ V}, V_{DD} = 2.7 \text{ to } 5.5 \text{ V}, \text{ Topr} = -40 \text{ to } 85^{\circ}\text{C})$$

Parameter	Oscillator	Oscillation	Recommended Oscillator		Recommended Constant	
		Frequency			C ₁	C ₂
High-frequency Oscillation	Ceramic Resonator	8 MHz	MURATA	CSA8.00MTZ	30 pF	30 pF
				CST8.00MTW	30 pF (built-in)	30 pF (built-in)
		4.19 MHz	MURATA	CSA4.19MG	30 pF	30 pF
				CST4.19MGW	30 pF (built-in)	30 pF (built-in)







(2) Low-frequency Oscillation

- Note 1: An electrical shield by metal shield plate on the surface of IC package is recommended in order to protect the device from the high electric field stress applied from CRT (Cathodic Ray Tube) for continuous reliable operation.
- Note 2: The product numbers and specifications of the resonators by Murata Manufacturing Co., Ltd. are subject to change. For up-to-date information, please refer to the following URL; http://www.murata.co.jp/search/index.html